Si7113ADN

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PRODUCT SUMMARY

 $R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V

 $R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V

V_{DS} (V)

I_D (A) ^g

Q_g typ. (nC)

Configuration

Vishay Siliconix



-100

0.132

0.186

5.65

10.8

Single

TrenchFET[®] power MOSFET

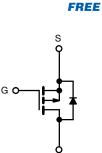
FEATURES

P-Channel 100 V (D-S) MOSFET

- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Active clamp in intermediate DC/DC power supplies
- LED Lighting
- Load switch



RoHS

COMPLIANT

HALOGEN

D P-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK 1212-8
Lead (Pb)-free and halogen-free	Si7113ADN-T1-GE3

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-100	v	
Gate-source voltage		V _{GS}	± 20		
	T _C = 25 °C		-10.8		
Continuous drain current ($T_J = 150 \ ^{\circ}C$)	T _C = 70 °C		-8.6		
	T _A = 25 °C	I _D	-3.8 ^{b, c}		
	T _A = 70 °C		-3.1 ^{b, c}	A	
Pulsed drain current (t = 100 µs)		I _{DM}	-20		
Continuous comes duris dis de coment	T _C = 25 °C	1	-16 ^a		
Continuous source-drain diode current	T _A = 25 °C	I _S	-2.9 ^{b, c}		
Single pulse avalanche current		I _{AS}	-15		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	11.25	mJ	
	T _C = 25 °C		27.8		
Manian and a disain stick	T _C = 70 °C		17.8	14/	
Maximum power dissipation	T _A = 25 °C	P _D	3.5 ^{b, c}	W	
	T _A = 70 °C	1	2.2 ^{b, c}		
Operating junction and storage temperature range		T _J , T _{stq}	-55 to +150	**	
Soldering recommendations (peak temperature) d, e			260		

THERMAL RESISTANCE RATING	as				
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^{b, f}	t ≤ 10 s	R _{thJA}	29	36	°C/W
Maximum junction-to-case (drain)	Steady state	R _{thJC}	3.6	4.6	6/00

Notes

Package limited а.

Surface mounted on 1" x 1" FR4 board b.

t = 10 s c.

See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components Maximum under steady state conditions is 81 °C/W d.

e.

f.

g. T_C = 25 °C

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	•						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-100	-	-	V	
V _{DS} temperature coefficient	$\Delta V_{DS}/T_{J}$		-	-63	-		
V _{GS(th)} temperature coefficient	$\Delta V_{GS(th)}/T_J$	I _D = -250 μA	-	4.2	-	mV/°C	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250 μA	-1.1	-	-2.6	V	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA	
		V _{DS} = -100 V, V _{GS} = 0 V	-	-	-1		
Zero gate voltage drain current	I _{DSS}	V _{DS} = -100 V, V _{GS} = 0 V, T _J = 70 °C	-	-	-10	μA	
On-state drain current ^a	I _{D(on)}	$V_{DS} \ge -10 \text{ V}, \text{ V}_{GS} = -10 \text{ V}$	-15	-	-	Α	
D · · · · · · · ·		V _{GS} = -10 V, I _D = -3.8 A	-	0.110	0.132		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V, I _D = -3.2 A	-	0.155	0.186	Ω	
Forward transconductance ^a	g _{fs}	V _{DS} = -10 V, I _D = -3.8 A	-	8	-	S	
Dynamic ^b				•			
Input capacitance	C _{iss}		-	515	-		
Output capacitance	C _{oss}	V _{DS} = -50 V, V _{GS} = 0 V, f = 1 MHz	-	162	-	pF	
Reverse transfer capacitance	C _{rss}		-	10	-		
Total gate charge	Qg	$V_{DS} = -50 \text{ V}, \text{ V}_{GS} = -10 \text{ V}, \text{ I}_{D} = -3.8 \text{ A}$	-	10.9	16.5		
			-	5.65	8.5		
Gate-source charge	Q _{qs}	V _{DS} = -50 V, V _{GS} = -4.5 V, I _D = -3.8 A	-	1.7	-	nC	
Gate-drain charge	Q _{gd}		-	2.5	-		
Gate resistance	Rg	f = 1 MHz	1.96	9.8	19.6	Ω	
Turn-on delay time	t _{d(on)}		-	10	20		
Rise time	t _r	V _{DD} = -50 V, R _I = 16.1 Ω, I _D ≅ -3.1 A,	-	22	40	-	
Turn-off delay time	t _{d(off)}	$V_{\text{GEN}} = -10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	20	40		
Fall time	t _f		-	20	40		
Turn-on delay time	t _{d(on)}		-	35	55	ns	
Rise time	t _r	V _{DD} = -50 V, R _I = 16.1 Ω, I _D ≅ -3.1 A,	-	40	60		
Turn-off delay time	t _{d(off)}	$V_{\text{GEN}} = -4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$	-	22	40		
Fall time	t _f		-	1622	40	1	
Drain-Source Body Diode Characteristi	cs						
Continuous source-drain diode current	IS	T _C = 25 °C	-	-	-16		
Pulse diode forward current	I _{SM}		-	-	-15	A	
Body diode voltage	V _{SD}	I _S = -3.1 A, V _{GS} = 0 V	-	-0.8	-1.2	V	
Body diode reverse recovery time	t _{rr}		-	43	65	ns	
Body diode reverse recovery charge	Q _{rr}		-	80	120	nC	
Reverse recovery fall time	t _a	$I_{\rm E} = -3.1 \text{ A}. \text{ d}/\text{d} \text{f} = 100 \text{ A}/\text{US}. 11 = 25 \text{ C}$		36	-		
Reverse recovery rise time	t _b		-	7	-	ns	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

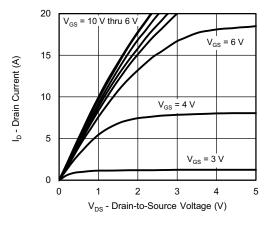
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

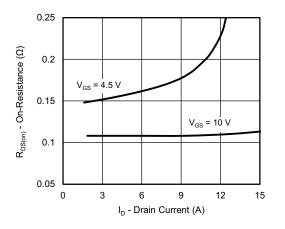
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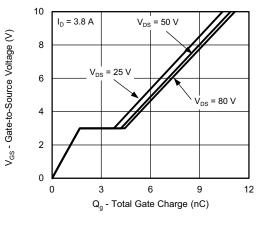
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



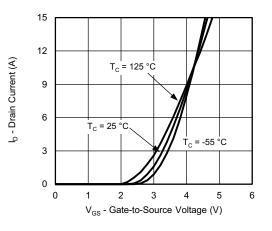
Output Characteristics



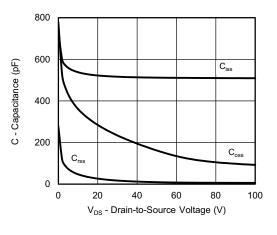
On-Resistance vs. Drain Current and Gate Voltage



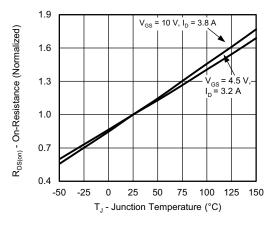
Gate Charge



Transfer Characteristics



Capacitance



On-Resistance vs. Junction Temperature

3

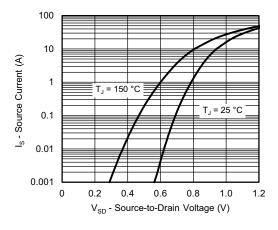
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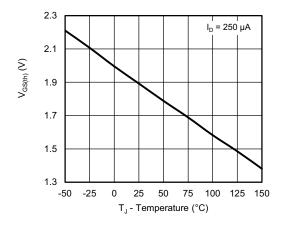
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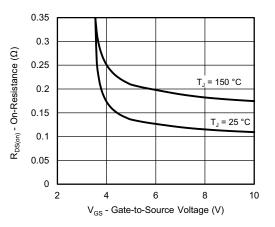
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



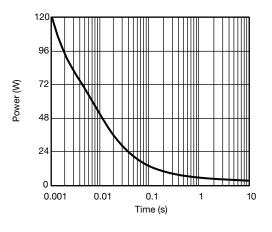
Source-Drain Diode Forward Voltage



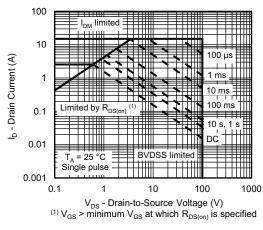
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient

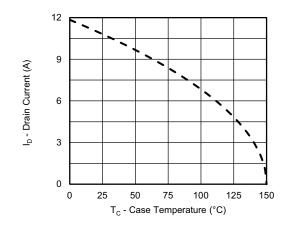
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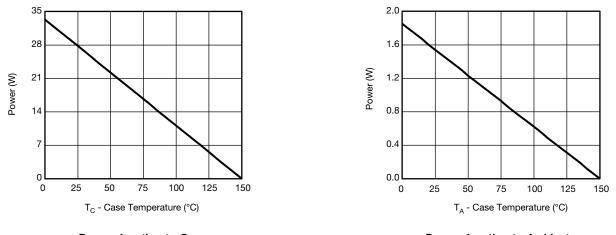
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating a



Power, Junction-to-Case

Power, Junction-to-Ambient

Note

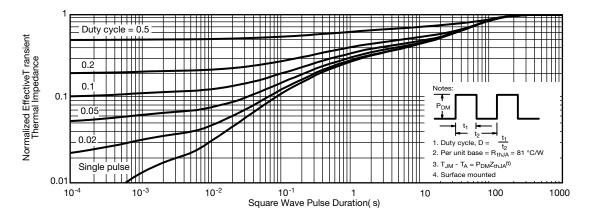
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

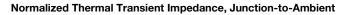


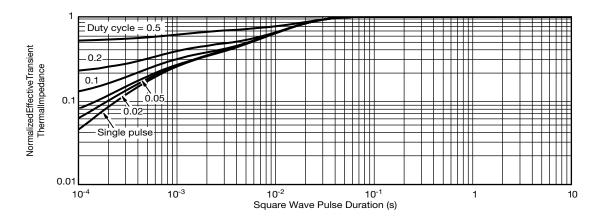
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







Normalized Thermal Transient Impedance, Junction-to-Case

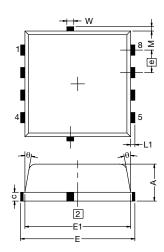
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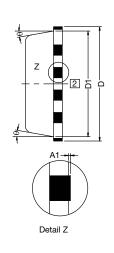
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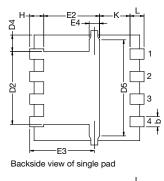


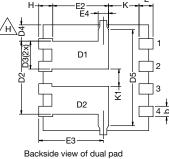
Document Number: 71656

PowerPAK® 1212-8, (Single / Dual)









Notes

1. Inch will govern

Dimensions exclusive of mold gate burrs
Dimensions exclusive of mold flash and cutting burrs

DIM.		MILLIMETERS		INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.97	1.04	1.12	0.038	0.041	0.044	
A1	0.00	-	0.05	0.000	-	0.002	
b	0.23	0.30	0.41	0.009	0.012	0.016	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	3.20	3.30	3.40	0.126	0.130	0.134	
D1	2.95	3.05	3.15	0.116	0.120	0.124	
D2	1.98	2.11	2.24	0.078	0.083	0.088	
D3	0.48	-	0.89	0.019	-	0.035	
D4		0.47 typ.	·	0.0185 typ			
D5		2.3 typ.			0.090 typ		
E	3.20	3.30	3.40	0.126	0.130	0.134	
E1	2.95	3.05	3.15	0.116	0.120	0.124	
E2	1.47	1.60	1.73	0.058	0.063	0.068	
E3	1.75	1.85	1.98	0.069	0.073	0.078	
E4		0.034 typ.		0.013 typ.			
е		0.65 BSC		0.026 BSC			
К		0.86 typ.		0.034 typ.			
K1	0.35	-	-	0.014	-	-	
Н	0.30	0.41	0.51	0.012	0.016	0.020	
L	0.30	0.43	0.56	0.012	0.017	0.022	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
М	0.125 typ.			0.005 typ.			
N: S16-2667-R /G: 5882	ev. M, 09-Jan-17						

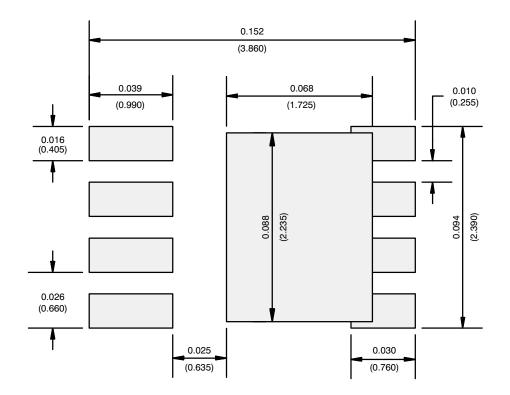
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RECOMMENDED MINIMUM PADS FOR PowerPAK[®] 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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